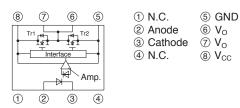


■ Internal Connection Diagram

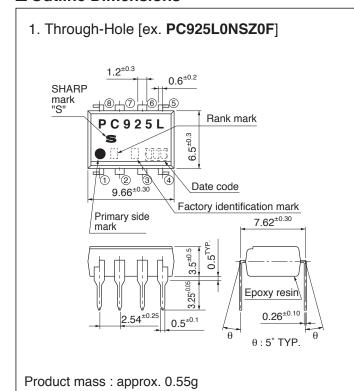


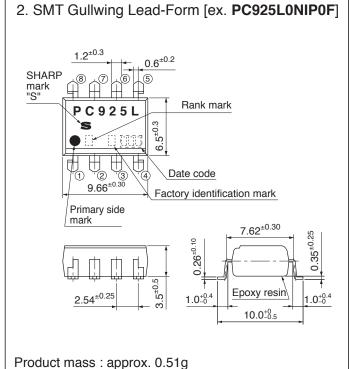
■ Truth table

Input	V _O Terminal output	Tr1	Tr2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

■ Outline Dimensions

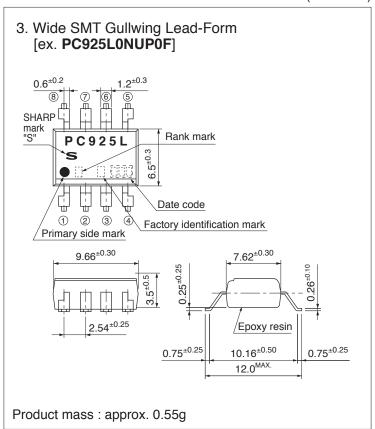
(Unit:mm)







(Unit: mm)



Plating material: Pd (Au flash)



Date code (3 digit)

	1st o	digit		2nd	digit	3rd	digit	
	Year of p	roduction		Month of production Week o		Week of p	production	
A.D.	Mark	A.D.	Mark	Month	Mark	Week	Mark	
1990	A	2002	P	January	1	1st	1	
1991	В	2003	R	February	2	2nd	2	
1992	С	2004	S	March	3	3rd	3	
1993	D	2005	T	April	4	4th	4	
1994	Е	2006	U	May	5	5, 6th	5	
1995	F	2007	V	June	6			
1996	Н	2008	W	July	7			
1997	J	2009	X	August	8			
1998	K	2010	A	September	9			
1999	L	2011	В	October	О			
2000	M	2012	С	November	N			
2001	N	:	:	December	D			

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin	
no mark	Ionan	
	- Japan	
or _	Indonesia	
or \	China	

^{*} This factory marking is for identification purpose only.

Please contact the local SHARP sales representative to see the actural status of the production.

Rank mark

With or without.



■ Absolute Maximum Ratings

	25	001
l I₂=	=23	()

	· · · · · · · · · · · · · · · · · · ·	_	(a = 0 0)	
	Parameter	Symbol	Rating	Unit
	*1 Forward current	I_F	25	mA
Input	Reverse voltage	V _R	5	V
	*2 Peak forward current	I_{FM}	1	A
	Supply voltage	V _{CC}	35	V
0	*3 Peak output current	I _{O(PEAK)}	2.5	A
Output	Output voltage	Vo	V _{CC}	V
	*4 Output power dissipation	Po	250	mW
*5 Total power dissipation		P _{tot}	295	mW
*6 Isolation voltage		V _{iso(rms)}	5	kV
Operating temperature		Topr	-40 to +100	°C
Storage temperature		T _{stg}	-55 to +125	°C
*7 Solde	ering temperature	T _{sol}	270	°C

^{*1} When ambient temperature goes above 70°C, the power dissipation goes down at $0.3 \text{mA/}^{\circ}\text{C}$ (Refer to Fig.10).

^{*2} Pulse width≤1µs, 300pps

^{*3} Pulse width≤10μs, Duty ratio: 0.002

*4 When ambient temperature goes above 70°C, the power dissipation goes down at 4.8mA/°C (Refer to Fig.11).

^{*5} When ambient temperature goes above 70°C, the power dissipation goes down at 5.4mA/°C (Refer to Fig.12).

^{*6} AC for 1min, 40 to 60%RH, f=60Hz

^{*7} For 10s



■ Electro-optical Characteristics*8

(Unless otherwise specified : $T_a=-+40$ to +100 °C, $I_{F(ON)}=7$ to 16mA, $V_{CC}=15$ to 30V, $V_{F(OFF)}=-3V$ to 0.8V)

		Parameter	Symbol	Condition	MIN.	*13 TYP.	MAX.	Unit
		Forward voltage	$V_{\rm F}$	I _F =10mA	1.2	-	1.8	V
Input		Reverse current	I_R	V _R =5V	_	_	10	μΑ
Π		Terminal capacitance	Ct	T _a =25°C, V=0, f=1MHz	_	60	150	pF
		High level output current	Ţ	*8 V _O =(V _{CC} -4V), I _{F(ON)}	0.5	1.5	_	A
		High level output current	I_{OH}	*9 V _O =(V _{CC} -15V), I _{F(ON)}	2	_	_	A
		Low level output current	I_{OL}	*8 V _O =2.5V, V _{F(OFF)}	0.5	2.0	-	A
		Low level output current	IOL	*9 V _O =15V, V _{F(OFF)}	2	-	_	A
Ħ		High level output voltage	V_{OH}	I_{O} =-0.1A, $I_{F(ON)}$	V _{CC} -4	V _{CC} -3	-	V
Output		Low level output voltage	V_{OL}	$I_O=0.1A,V_{F(OFF)}$	_	0.1	0.5	V
0		High level supply current	I_{CCH}	$I_{F(ON)}$	_	2.5	5	mA
	*10	Low level supply current	I_{CCL}	${ m V}_{ m F(OFF)}$	_	2.5	5	mA
		UVLO threshold	V _{UVLO+}		11	12.3	13.5	V
	UVLO inresnoid		V_{UVLO-} $V_O>5V, I_F=10mA$		9.5	10.7	12	V
		UVLO Hysteresis	$UVLO_{HYS}$		_	1.6	_	V
	*11	"Low-High" threshold input current	I_{FLH}	$V_{O} > 5V, I_{O} = 0$	_	_	5	mA
		Isolation resistance	R _{ISO}	$T_a=25$ °C, DC=500V, 40 to 60%RH	5×10 ¹⁰	10 ¹¹	-	Ω
		"Low→High" propagation time	t_{PLH}		0.1	0.3	0.5	μs
S		"High→Low" propagation time	t_{PHL}		0.1	0.3	0.5	μs
stic	ime	*12 Distortion of pulse width	Δt_{W}	$R_G=10\Omega$, $C_G=10nF$,	_	-	0.3	μs
teri	Response time	Propagation delay skew	t_{PSK}	f=10kHz, Duty ratio 50%	-0.35	-	0.35	μs
ara(pon	Rise time	t _r		_	0.1	_	μs
c ch	Res	Fall time	$t_{\rm f}$		_	0.1	_	μs
Transfer characteristics		UVLO Turn on delay	t _{UVLO ON}	$V_O > 5V$, $I_F = 10mA$	_	0.8	_	μs
[ran		UVLO Turn off delay	t _{UVLO OFF}	$V_O > 5V$, $I_F = 10$ mA	_	0.6		μs
	In	stantaneous common mode rejection	ICM _H I	$T_a=25$ °C, $V_{CM}=1.5kV(p-p)$,	15			kV/μs
	VC	ltage (High level output)	ICIVIHI	$I_F=10$ to 16mA, $V_{CC}=30V$, $V_{OH}>15V$	13	_	_	κv/μs
	In	stantaneous common mode rejection	ICM _L I	$T_a=25$ °C, $V_{CM}=1.5kV(p-p)$,	15	-	_	kV/μs
	VC	ltage (Low level output)	ICIVILI	$V_{F}=0, V_{CC}=30V, V_{OL}<1V$	15			κν/μδ

^{*7} It shall connect a by-pass capacitor of $0.1\mu F$ or more between V_{CC} (Pin No. 8) and GND (Pin No. 5) near the device, when it measures the transfer characteristics and the output side characteristics.

^{*8} Pulse width≤50μs, Duty ratio : 0.005

^{*9} Pulse width≤10μs, Duty ratio : 0.002

^{*10} Output pin is open.

^{*11} I_{FLH} is the value of forward current when output becomes from "L" to "H"

^{*12} Distortion of pulse width $\Delta t_W = |t_{PHL} - t_{PLH}|$

^{*13} All typical values are at T_a=25°C, V_{CC}=30V



■ Model Line-up

Lead Form	Through-Hole	SMT Gullwing Wide SMT Gullwing	
Package	Sleeve	Taping	
	50 pcs/sleeve	1 000 pcs/reel	
Model No.	PC925L0NSZ0F	PC925L0NIP0F	PC925L0NUP0F



Fig.1 Test Circuit for High Level Output Current

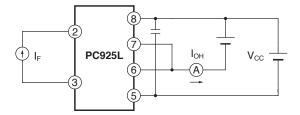


Fig.2 Test Circuit for Low Level Output Current

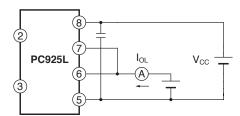


Fig.3 Test Circuit for High Level Output Voltage

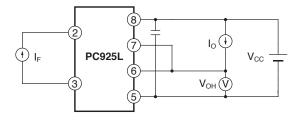


Fig.4 Test Circuit for Low Level Output Voltage

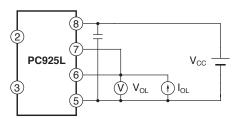


Fig.5 Test Circuit for High Level / Low Level Supply Current

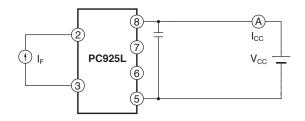


Fig.6 Test Circuit for UVLO Threshold

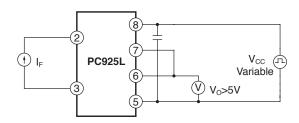




Fig.7 Test Circuit for "Low→High" Input Threshold Current

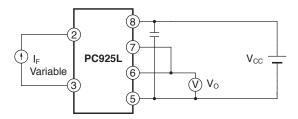
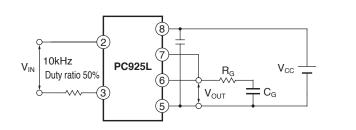


Fig.8 Test Circuit for Response Time



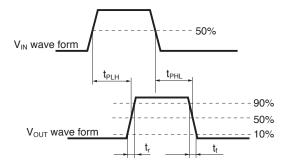


Fig.9 Test Circuit for Instantaneous Common Mode Rejection Voltage

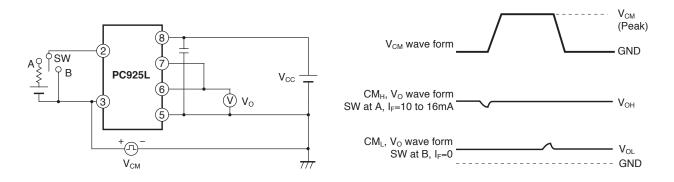




Fig.10 Forward Currenet vs.
Ambient Temperature

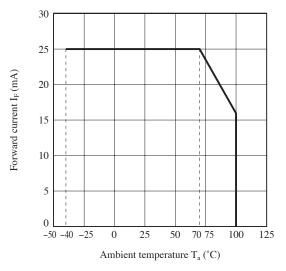


Fig.12 Total Power Dissipation vs.
Ambient Temperature

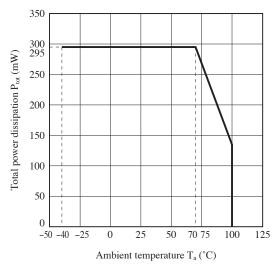


Fig.14 High Level Output Voltage Drop vs.

Ambient Temperature

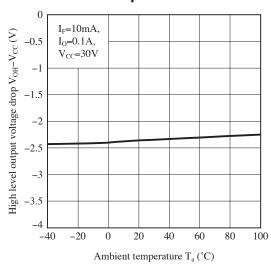


Fig.11 Power Dissipation vs.
Ambient Temperature

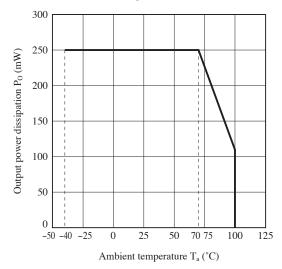


Fig.13 Forward Current vs. Forward Voltage

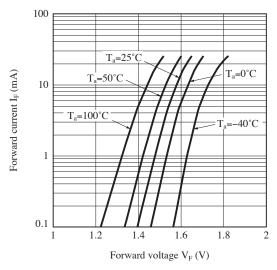


Fig.15 High Level Output Voltage Drop vs. Supply Voltage

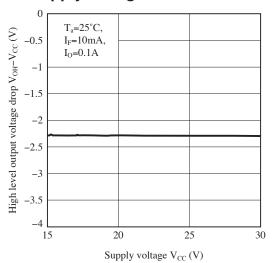




Fig.16 Low Level Output Voltage vs.
Ambient Temperature

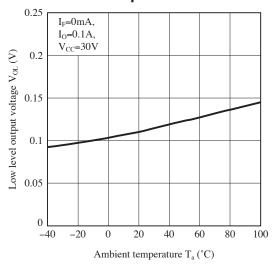


Fig.18 High Level Supply Current vs.
Ambient Temperature

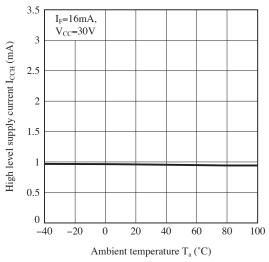


Fig.20 Low Level Supply Current vs.

Ambient Temperature

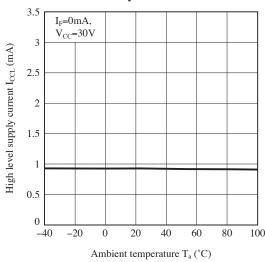


Fig.17 Low Level Output Voltage vs. Supply Voltage

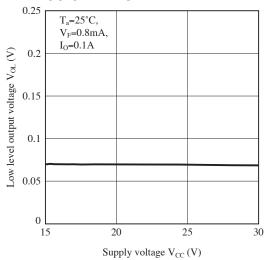


Fig.19 High Level Supply Current vs. Supply Voltage

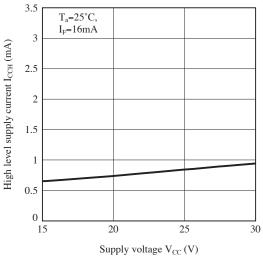


Fig.21 Low Level Supply Current vs. Supply Voltage

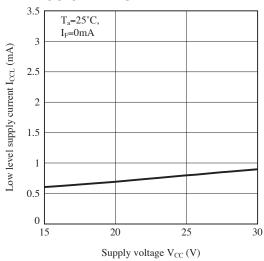




Fig.22 "Low→High" Relative Threshold Input Current vs. Ambient Temperature

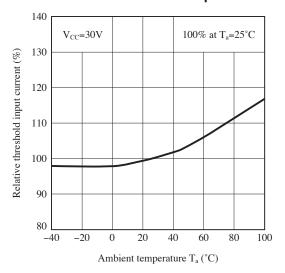


Fig.24 Output Voltage vs. Supply Voltage (UVLO Threshold)

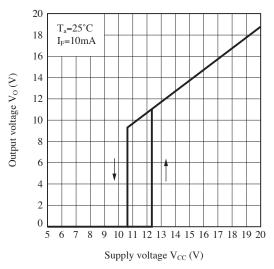


Fig.26 Propagation Delay Time vs.
Ambient Temperature

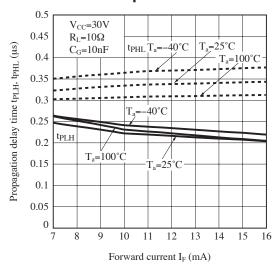


Fig.23 "Low→High" Relative Threshold Input Current vs. Supply Voltage

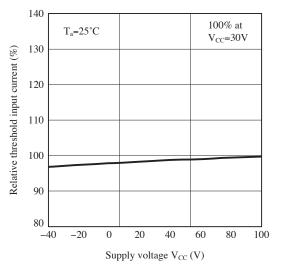
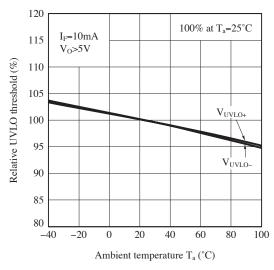


Fig.25 Relative UVLO Threshold vs. Ambient Temperature



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Recommended Operating Conditions

Parameter	Symbol	MIN.	MAX.	Unit
Input current (ON)	I _F (ON)	7	16	mA
Input voltage (OFF)	V _F (OFF)	-3	0.8	V
Supply voltage	V _{CC}	15	30	V
Operating temperature	Topr	-40	100	°C

Notes about static electricity

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

Design guide

In order to stabilize power supply line, please certainly connect a by-pass capacitor of $0.1\mu F$ or more between V_{CC} and GND near the device.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through LED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of LED.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

This product is not designed against irradiation and incorporates non-coherent LED.

Degradation

In general, the emission of the LED used in photocouplers will degrade over time.

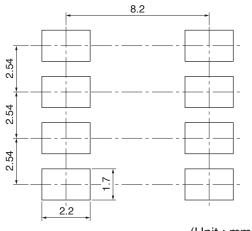
In the case of long term operation, please take the general LED degradation (50% degradation over 5 years) into the design consideration.

Please decide the input current which become 2 times of MAX. I_{FLH}.



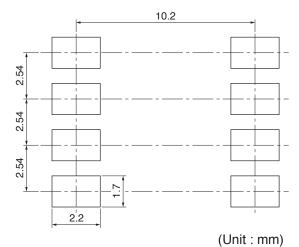
Recommended Foot Print (reference)

SMT Gullwing Lead-form



(Unit: mm)

Wide SMT Gullwing Lead-form



[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

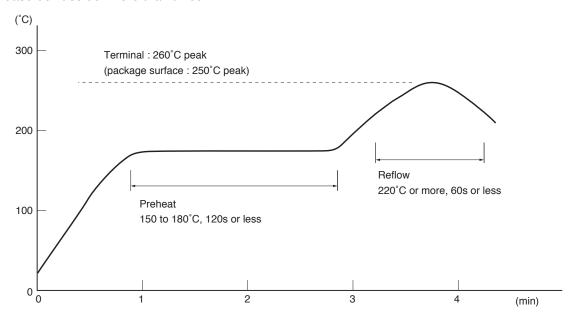
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3 s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3minutes or less.

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC etc.

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1,1,1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

• The RoHS directive (2002/95/EC)

This product complies with the RoHS directive (2002/95/EC).

Object substances: lead, mercury, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE)

• Content of six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (Chinese: 电子信息产品污染控制管理办法)

		Toxic and hazardous substances					
Category	Lead (Pb)	Mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr(VI))	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)	
Photocoupler	~	~	~	V	V	V	

✓: indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.



■ Package specification

Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

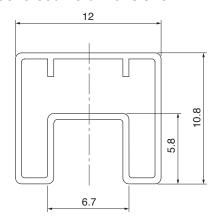
MAX. 50pcs of products shall be packaged in a sleeve.

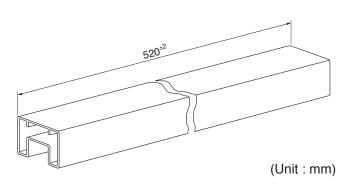
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions







● Tape and Reel package

1. SMT Gullwing Lead-Form

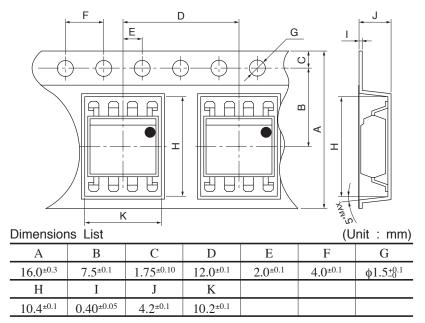
Package materials

Carrier tape: A-PET (with anti-static material)

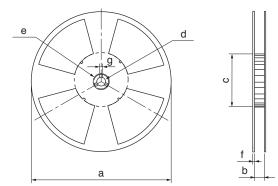
Cover tape: PET (three layer system)

Reel: PS

Carrier tape structure and Dimensions

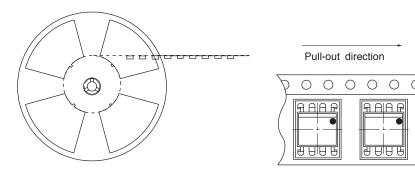


Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
ф330	17.5 ^{±1.5}	φ100±1	φ13.0±0.5	
e	f	g		
φ23±1	2.0±0.5	2.0±0.5		

Direction of product insertion



[Packing: 1 000pcs/reel]



● Tape and Reel package

2. Wide SMT Gullwing Lead-Form

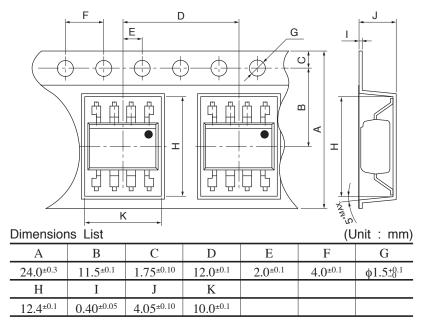
Package materials

Carrier tape: A-PET (with anti-static material)

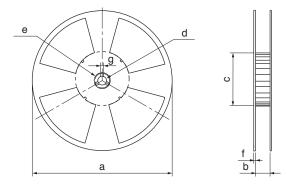
Cover tape: PET (three layer system)

Reel: PS

Carrier tape structure and Dimensions

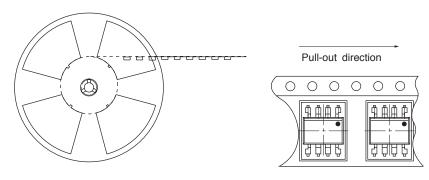


Reel structure and Dimensions



Dimensio	ns List	(U	nit : mm)
a	b	с	d
φ330	25.5±1.5	φ100±1	ф13.0±0.5
e	f	g	
ф23±1	2.0±0.5	2.0±0.5	

Direction of product insertion



[Packing: 1 000pcs/reel]



■ Important Notices

- · The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.
- · Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.
- · Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:
- (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - --- Personal computers
 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - --- Space applications
 - --- Telecommunication equipment [trunk lines]
 - --- Nuclear power control equipment
 - --- Medical and other life support equipment (e.g., scuba).
- · If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.
- This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.
- \cdot Contact and consult with a SHARP representative if there are any questions about the contents of this publication.